

Features

- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

Typical Applications

- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers

$I_{F(AV)}$	1700 A
V_{RRM}	200~1000 V
I_{FSM}	18 KA
I^2t	1620 10³A²S



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Double side cooled,	T _c =55°C			1990	A
			T _c =85°C			1700	
V _{RRM}	Repetitive peak reverse voltage	V _{RRM} tp=10ms V _{RSM} = V _{RRM} +100V	190	200		1000	V
I _{RRM}	Repetitive peak current	V _{RM} = V _{RRM}	190			40	mA
I _{FSM}	Surge forward current	10ms half sine wave	190			18	KA
I ² t	I ² T for fusing coordination	V _R =0.6V _{RRM}				1620	A ² s*10 ³
V _{FO}	Threshold voltage		190			0.81	V
r _F	Forward slop resistance					0.23	mΩ
V _{FM}	Peak on-state voltage	I _{FM} =4400A, F=15KN	190			1.82	V
Q _{rr}	Recovery charge	I _{FM} =2000A, tp=2000μs, di/dt=-20A/μs, V _R =50V	190		1900		μC
R _{th(j-c)}	Thermal resistance Junction to case	At 180° sine double side cooled Clamping force 15.0KN				0.035	°C /W
R _{th(c-h)}	Thermal resistance case to heat sink					0.008	
F _m	Mounting force			10		20	KN
T _{stg}	Stored temperature			-40		190	°C
W _t	Weight				240		g
Outline	ZT33cT						

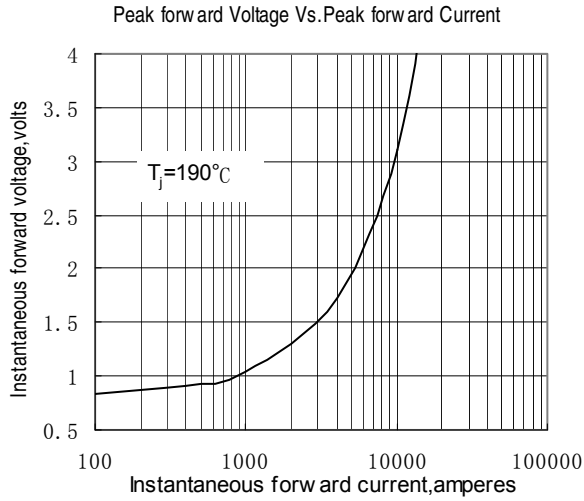


Fig.1

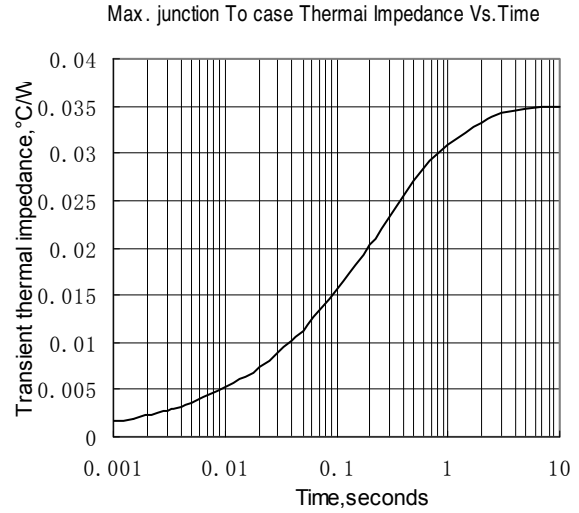


Fig.2

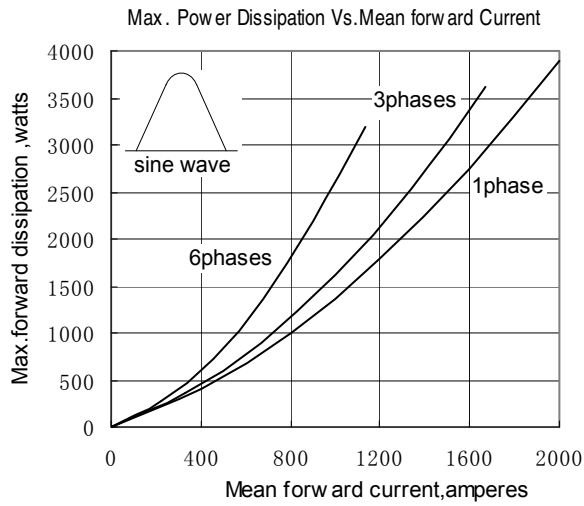


Fig.3

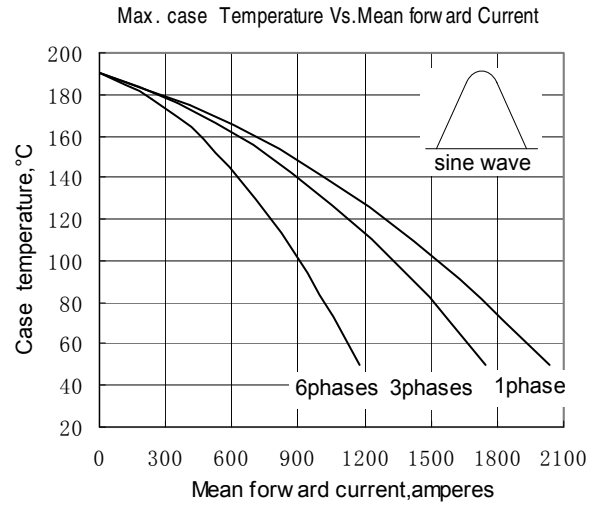


Fig.4

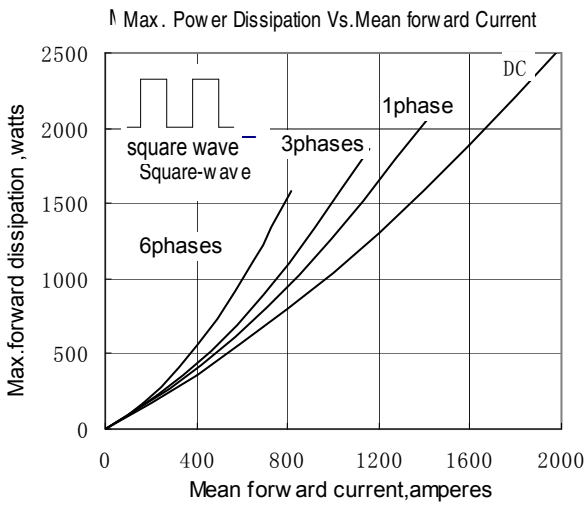


Fig.5

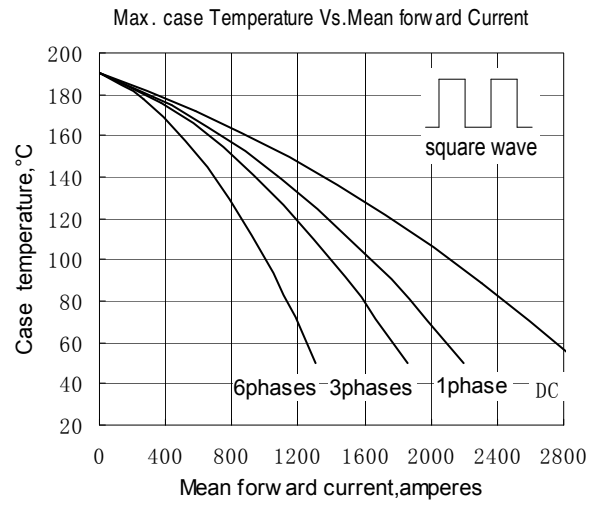


Fig.6

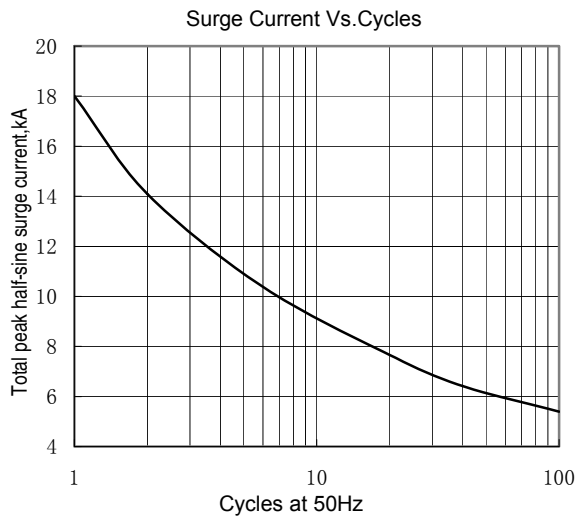


Fig.7

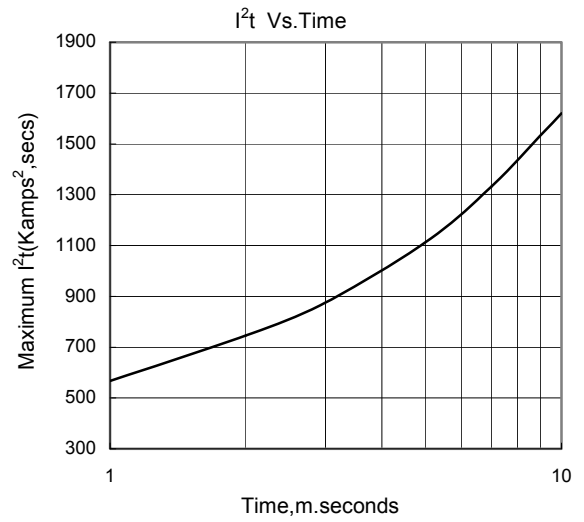


Fig.8

Outline:

